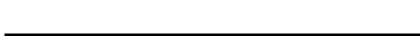
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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR NP34N055HLE, NP34N055ILE, NP34N055SLE

SWITCHING N-CHANNEL POWER MOSFET

DESCRIPTION

These products are N-Channel MOS Field Effect Transistors designed for high current switching applications.

FEATURES

- Channel temperature 175 degree rated
- Super low on-state resistance

 $R_{DS(on)1}$ = 18 m Ω MAX. (Vgs = 10 V, ID = 17 A)

 $R_{DS(on)2} = 22 \text{ m}\Omega \text{ MAX.} (V_{GS} = 5 \text{ V}, I_D = 17 \text{ A})$

- Low Ciss : Ciss = 2000 pF TYP.
- · Built-in gate protection diode

★ ORDERING INFORMATION

PART NUMBER	PACKAGE
NP34N055HLE	TO-251 (JEITA) / MP-3
NP34N055ILE Note	TO-252 (JEITA) / MP-3Z
NP34N055SLE	TO-252 (JEDEC) / MP-3ZK

(TO-251)

Note Not for new design.

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage	Voss	55	V
Gate to Source Voltage	Vgss	±20	V
Drain Current (DC)	ID(DC)	±34	Α
Drain Current (Pulse) Note1	ID(pulse)	±136	Α
Total Power Dissipation (T _A = 25°C)	Рт	1.2	W
Total Power Dissipation (Tc = 25°C)	Рт	88	W
Single Avalanche Current Note2	las	34 / 27 / 10	Α
Single Avalanche Energy Note2	Eas	11 / 72 / 100	mJ
Channel Temperature	Tch	175	°C
Storage Temperature	Tstg	-55 to + 175	°C

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting T_{ch} = 25°C, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V (See Figure 4.)

THERMAL RESISTANCE

Channel to Case Thermal Resistance	Rth(ch-C)	1.70	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A)	125	°C/W

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ELECTRICAL CHARACTERISTICS (TA = 25°C)

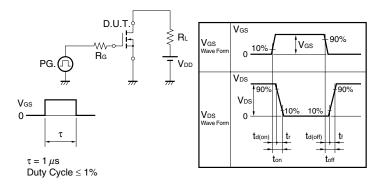
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 55 V, V _{GS} = 0 V			10	μΑ
Gate Leakage Current	Igss	V _{GS} = ±20 V, V _{DS} = 0 V			±10	μΑ
Gate to Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.5	2	2.5	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = 10 V, I _D = 17 A	9	19		S
Drain to Source On-state Resistance Note	RDS(on)1	V _{GS} = 10 V, I _D = 17 A		14	18	mΩ
	RDS(on)2	V _{GS} = 5 V, I _D = 17 A		17	22	mΩ
	RDS(on)3	V _{GS} = 4.5 V, I _D = 17 A		18	24	mΩ
Input Capacitance	Ciss	V _{DS} = 25 V		2000	3000	pF
Output Capacitance	Coss	V _{GS} = 0 V		250	380	pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		130	230	pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 28 V, I _D = 17 A		17	37	ns
Rise Time	t r	V _{GS} = 10 V		11	28	ns
Turn-off Delay Time	t d(off)	R _G = 1 Ω		57	110	ns
Fall Time	t _f			9	23	ns
Total Gate Charge	Q _{G1}	V _{DD} = 44 V, V _{GS} = 10 V, I _D = 34 A		41	72	nC
	Q _{G2}	V _{DD} = 44 V		23	35	nC
Gate to Source Charge	Qgs	V _{GS} = 5 V		7		nC
Gate to Drain Charge	Q _{GD}	I _D = 34 A		12		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	I _F = 34 A, V _{GS} = 0 V		1.0		V
Reverse Recovery Time	trr	I _F = 34 A, V _{GS} = 0 V		42		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		58		nC

Note Pulsed

TEST CIRCUIT 1 AVALANCHE CAPABILITY

$V_{GS} = 20 \rightarrow 0 \text{ V}$ V_{DD} V_{DD}

TEST CIRCUIT 2 SWITCHING TIME



TEST CIRCUIT 3 GATE CHARGE

TYPICAL CHARACTERISTICS (TA = 25°C)



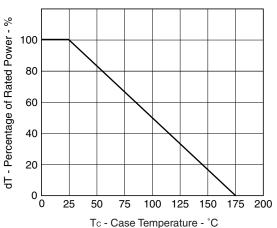


Figure 3. FORWARD BIAS SAFE OPERATING AREA

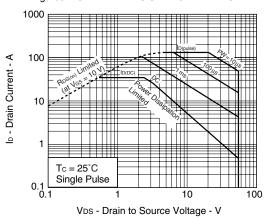


Figure 2. TOTAL POWER DISSIPATION vs.

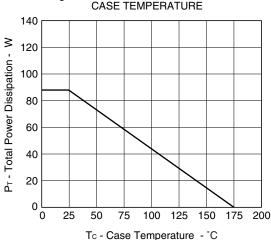


Figure4. SINGLE AVALANCHE ENERGY DERATING FACTOR

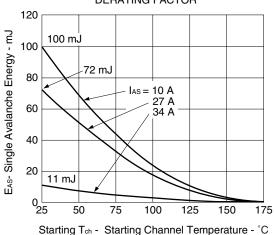


Figure 5. TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

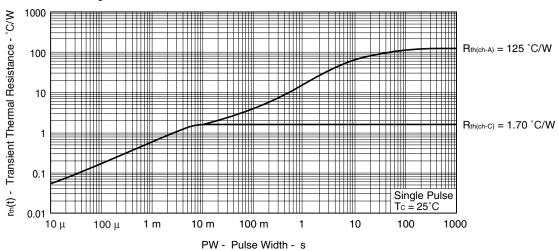


Figure 6. FORWARD TRANSFER CHARACTERISTICS

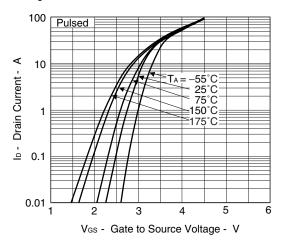
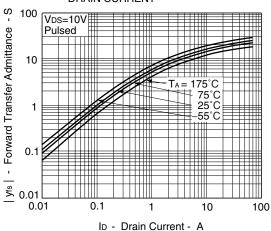


Figure 8. FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



R_{DS(on)} - Drain to Source On-state Resistance - mΩ 40 Pulsed 35 30 Vgs = 10 V 5 V 25 4.5 V 20 15

Figure 10. DRAIN TO SOURCE ON-STATE

RESISTANCE vs. DRAIN CURRENT

100 ID - Drain Current - A

Figure 7. DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE

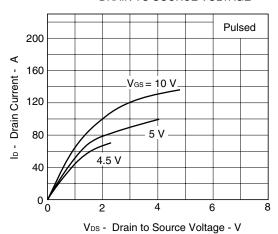


Figure 9. DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

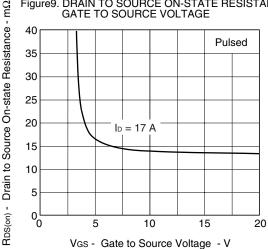
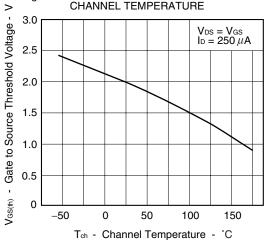


Figure 11. GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE

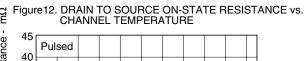


10

5

0

1000



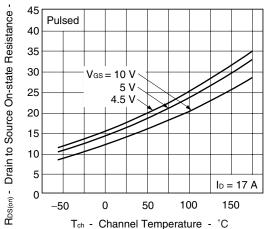


Figure 14. CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE

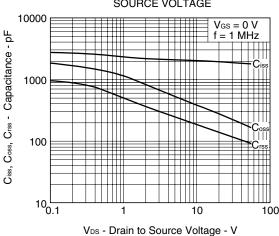


Figure 16. REVERSE RECOVERY TIME vs. DRAIN CURRENT

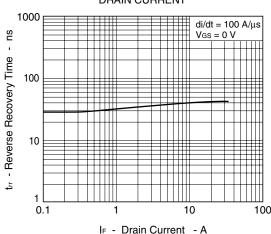


Figure 13. SOURCE TO DRAIN DIODE FORWARD VOLTAGE

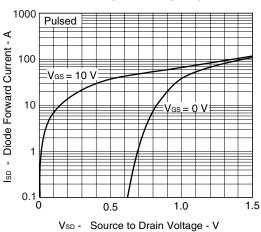


Figure 15. SWITCHING CHARACTERISTICS

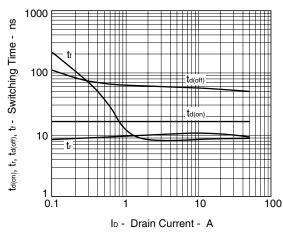
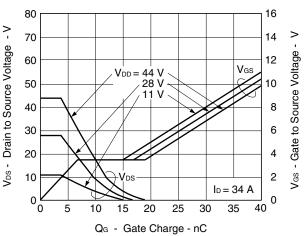
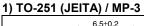
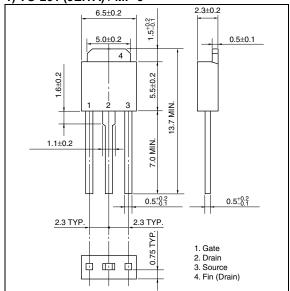


Figure 17. DYNAMIC INPUT/OUTPUT CHARACTERISTICS

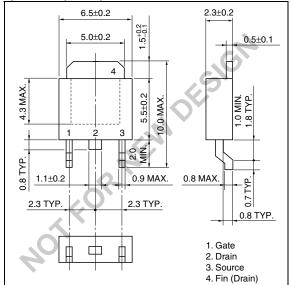


PACKAGE DRAWINGS (Unit: mm)

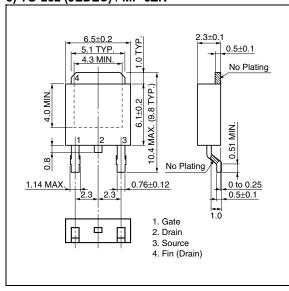




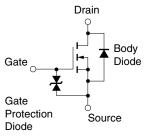
2) TO-252 (JEITA) / MP-3Z



3) TO-252 (JEDEC) / MP-3ZK



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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